

PRESS RELEASE
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Local Small Business Secures Patent on Power Amplifier Component for Wireless Communication Devices

Chicago, IL - MicroLink Devices, Inc. (MicroLink), www.mldevices.com, a Niles, IL based manufacturer of compound semiconductor materials for heterojunction bipolar transistors (HBT) and solar cells, is proud to announce the issuance of U.S. Patent No. 7,687,886 "High on-state breakdown heterojunction bipolar transistor."

MicroLink's HBT technology has been an established contributor to the advancement of wireless communications since 2000. The patent protects MicroLink's unique design of a composite collector on a Gallium-Indium Phosphide (GaInP) HBT. This design has the potential to dramatically improve the performance of a variety of electronic components, particularly power amplifiers in any radio frequency (RF) device.

Dr. Noren Pan, CEO and founder of MicroLink Devices, has said "This is a fundamental technology for wireless communications applications, enabling power amplifiers with higher output power and the ability to tolerate a large impedance mismatch."

About MicroLink Devices, Inc (MLD)

Dr. Pan founded MLD in 2000. The epitaxial wafers produced by MicroLink have been an essential component in the high speed communication industries. The company has earned the ISO 9001 Certification for their quality and service practices and has been a federal contractor of transistors, lasers and solar cell projects for the past six years. MLD has collaborated with many other companies' research and development projects with many of the initiatives becoming widely-used commercial products.

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